

HIGH SPEED 2K x 8 DUAL PORT STATIC RAM

IDT7132SA/LA IDT7142SA/LA

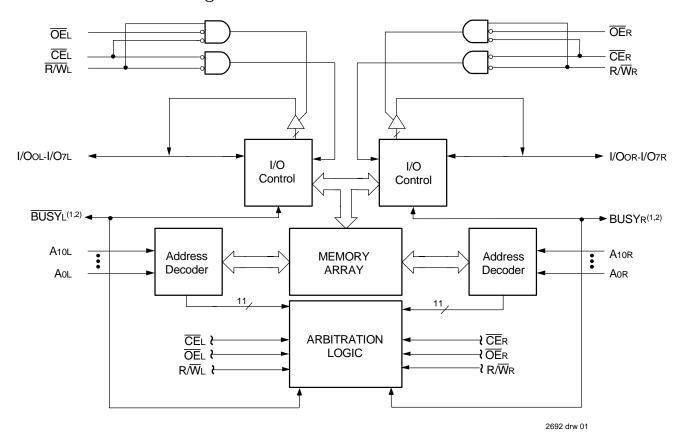
LEAD FINISH (SnPb) ARE IN EOL PROCESS - LAST TIME BUY EXPIRES JUNE 15, 2018

Features

- High-speed access
 - Commercial: 20/25/35/55/100ns (max.)
 - Industrial: 25ns (max.)
 - Military: 25/35/55/100ns (max.)
- Low-power operation
 - IDT7132/42SA Active: 325mW (typ.) Standby: 5mW (typ.)
 - IDT7132/42LA Active: 325mW (typ.) Standby: 1mW (typ.)

- MASTER IDT7132 easily expands data bus width to 16-or-more bits using SLAVE IDT7142
- On-chip port arbitration logic (IDT7132 only)
- ◆ BUSY output flag on IDT7132; BUSY input on IDT7142
- ◆ Battery backup operation —2V data retention (LA only)
- ◆ TTL-compatible, single 5V ±10% power supply
- Available in 48-pin DIP, LCC and Flatpack, and 52-pin PLCC packages
- Military product compliant to MIL-PRF-38535 QML
- Industrial temperature range (-40°C to +85°C) is available for selected speeds
- Green parts available, see ordering information

Functional Block Diagram



NOTES:

- IDT7132 (MASTER): BUSY is open drain output and requires pullup resistor of 270Ω.
 IDT7142 (SLAVE): BUSY is input.
- 2. Open drain output: requires pullup resistor of 270 $\!\Omega$.

JULY 2018

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Description

The IDT7132/IDT7142 are high-speed 2K x 8 Dual-Port Static RAMs. The IDT7132 is designed to be used as a stand-alone 8-bit Dual-Port RAM or as a "MASTER" Dual-Port RAM together with the IDT7142 "SLAVE" Dual-Port in 16-bit-or-more word width systems. Using the IDT MASTER/ SLAVE Dual-Port RAM approach in 16-or-more-bit memory system applications results in full-speed, error-free operation without the need for additional discrete logic.

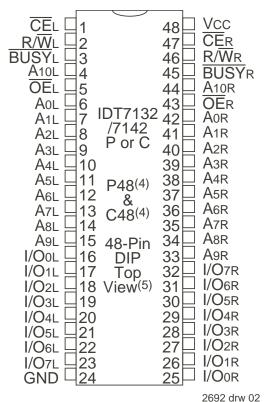
Both devices provide two independent ports with separate control, address, and I/O pins that permit independent, asynchronous access for reads or writes to any location in memory. An automatic power down feature, controlled by $\overline{\text{CE}}$ permits the on-chip circuitry of each port to enter

a very low standby power mode.

Fabricated using CMOS high-performance technology, these devices typically operate on only 325mW of power. Low-power (LA) versions offer battery backup data retention capability, with each Dual-Port typically consuming 200µW from a 2V battery.

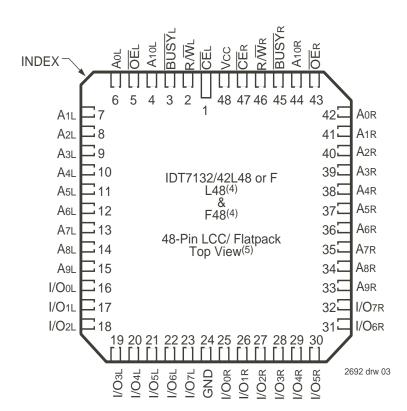
The IDT7132/7142 devices are packaged in a 48-pin sidebraze or plastic DIPs, 48-pin LCCs, 52-pin PLCCs, and 48-lead flatpacks. Military grade product is manufactured in compliance with the latest revision of MIL-PRF-38535 QML, making it ideally suited to military temperature applications demanding the highest level of performance and reliability.

Pin Configurations^(1,2,3)



NOTES:

- 1. All Vcc pins must be connected to the power supply.
- 2. All GND pins must be connected to the ground supply.
- P48-1 package body is approximately .55 in x 2.43 in x .18 in. C48-2 package body is approximately .62 in x 2.43 in x .15 in. L48-1 package body is approximately .57 in x .57 in x .68 in. F48-1 package body is approximately .75 in x .75 in x .11 in.
- 4. This package code is used to reference the package diagram.
- 5. This text does not indicate orientation of the actual part-marking.



Capacitance⁽¹⁾ (TA = +25°C,f = 1.0MHz)

| Symbol | Parameter | Conditions ⁽²⁾ | Max. | Unit |
|--------|--------------------|---------------------------|------|------|
| Cin | Input Capacitance | VIN = 3dV | 11 | pF |
| Соит | Output Capacitance | Vout = 3dV | 11 | pF |

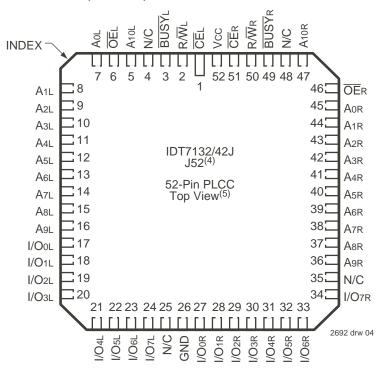
NOTES:

. This parameter is determined by device characterization but is not production tested.

2692 tbl 00

3dV represents the interpolated capacitance when the input and output signals switch from 3V to 0V.

Pin Configurations^(1,2,3) (con't.)



NOTES:

- 1. All Vcc pins must be connected to the power supply.
- 2. All GND pins must be connected to the ground supply.
- 3. Package body is approximately .75 in x .75 in x .17 in.
- 4. This package code is used to reference the package diagram.
- 5. This text does not indicate orientation of the actual part-marking.

Absolute Maximum Ratings(1)

| Absolute Maximam Ratings | | | | | | | | | |
|--------------------------|--------------------------------------|----------------------------|--------------|------|--|--|--|--|--|
| Symbol | Rating | Commercial & Industrial | Military | Unit | | | | | |
| VTERM ⁽²⁾ | Terminal Voltage with Respect to GND | -0.5 to +7.0 | -0.5 to +7.0 | V | | | | | |
| TBIAS | Temperature Under Bias | -55 to +125 | -65 to +135 | °C | | | | | |
| Tstg | Storage Temperature | -65 to +150 | -65 to +150 | °C | | | | | |
| lout | DC Output Current | 50 | 50 | mA | | | | | |

NOTES:

Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may
cause permanent damage to the device. This is a stress rating only and functional
operation of the device at these or any other conditions above those indicated in
the operational sections of the specification is not implied. Exposure to absolute
maximum rating conditions for extended periods may affect reliability.

2. VTERM must not exceed Vcc + 10% for more than 25% of the cycle time or 10ns maximum, and is limited to ≤ 20mA for the period of VTERM ≥ Vcc + 10%.

Recommended Operating Temperature and Supply Voltage^(1,2)

| Grade | Ambient Temperature | GND | Vcc |
|------------|------------------------|-----|-------------------|
| Military | -55°C to+125°C | 0V | 5.0V <u>+</u> 10% |
| Commercial | 0°C to +70°C | 0V | 5.0V <u>+</u> 10% |
| Industrial | -40°C to +85°C | 0V | 5.0V <u>+</u> 10% |

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NOTES:

- 1. This is the parameter Ta. This is the "instant on" case temperature.
- Industrial temperature: for specific speeds, packages and powers contact your sales office.

Recommended DC Operating Conditions

| Symbol | Parameter | Min. | Тур. | Max. | Unit |
|--------|--------------------|---------------------|------|--------|------|
| Vcc | Supply Voltage | 4.5 | 5.0 | 5.5 | V |
| GND | Ground | 0 | 0 | 0 | V |
| V⊪ | Input High Voltage | 2.2 | | 6.0(2) | V |
| VIL | Input Low Voltage | -0.5 ⁽¹⁾ | _ | 0.8 | V |

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NOTES:

- V_I (min.) = -1.5V for pulse width less than 10ns.
- 2. VTERM must not exceed Vcc + 10%.

2692 tbl 01

DC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range $^{(1,5,8)}$ (Vcc = 5.0V \pm 10%)

| | | | <u> </u> | | • | | | | | | |
|----------|---|---|--------------|----------|------------|--|-------------|--|-------------|--------------------------------|------|
| | | | | | 7142 | X20 ⁽²⁾ X20 ⁽²⁾ I Only | 7142 Com | X25 ⁽⁷⁾ X25 ⁽⁷⁾ 'I, Ind Ilitary | 714: Con | 2X35 2X35 n'l & itary | |
| Symbol | Parameter | Test Condition | Vers | ion | Тур. | Max. | Тур. | Max. | Тур. | Max. | Unit |
| lcc | Dynamic Operating Current (Both Ports Active) | CEL = CER = VIL, Outputs Disabled f = fMAX ⁽³⁾ | COM'L | SA LA | 110 110 | 250 200 | 110 110 | 220 170 | 80 80 | 165 120 | mA |
| | | II = IMAX [©] | MIL & IND | SA LA | | | 110 110 | 280 220 | 80 80 | 230 170 | |
| ISB1 | Standby Current (Both Ports - TTL $f = \overline{CE}L = \overline{CE}R = VIH$, Level Inputs) | | COM'L | SA LA | 30 30 | 65 45 | 30 30 | 65 45 | 25 25 | 65 45 | mA |
| Level in | Lever inputs) | ver ilipus) | MIL & IND | SA LA | | _ | 30 30 | 80 60 | 25 25 | 80 60 | |
| ISB2 | Standby Current (One Port - TTL | CE"A" = VIL and CE"B" = VIH ⁽⁶⁾ Active Port Outputs Disabled | COM'L | SA LA | 65 65 | 165 125 | 65 65 | 150 115 | 50 50 | 125 90 | mA |
| | Level Inputs) f=fMAX ⁽³⁾ | MIL & IND | SA LA | _ | _ | 65 65 | 160 125 | 50 50 | 150 115 | | |
| ISB3 | Full Standby Current (Both Ports - All CMOS Level Inputs) | $\overline{\text{CE}}\text{L}$ and $\overline{\text{CE}}\text{R} \ge \text{VCC -0.2V}$ VIN $\ge \text{VCC -0.2V}$ or VIN $\le 0.2\text{V}$, f = $0^{(4)}$ | COM'L | SA LA | 1.0 0.2 | 15 5 | 1.0 0.2 | 15 5 | 1.0 0.2 | 15 4 | mA |
| | Civios Level inpuls) | vel Inputs) | MIL & IND | SA LA | | _ | 1.0 0.2 | 30 10 | 1.0 0.2 | 30 10 | |
| ISB4 | (One Port - All VIN > VCC - 0.2V or VIN < | \overline{CE} "A" $\leq 0.2V$ and \overline{CE} "B" $\geq VCC - 0.2V^{(6)}$ $VIN \geq VCC - 0.2V$ or $VIN \leq 0.2V$ | COM'L | SA LA | 60 60 | 155 115 | 60 60 | 145 105 | 45 45 | 110 85 | mA |
| | ČMOS Level Inputs) | Active Port Outputs Disabled f = fmax ⁽³⁾ | MIL & IND | SA LA | _ | | 60 60 | 155 115 | 45 45 | 145 105 | |

2692 tbl 04a

2692 tbl 04b

| | | | | | 7132X55 7132X 7142X55 7142X Com'l & Com Military Milit | | X100 n'l & | | |
|--------|---|--|--------------|----------|---|------------|---------------|------------|------|
| Symbol | Parameter | Test Condition | Versi | on | Тур. | Max. | Тур. | Max. | Unit |
| Icc | Dynamic Operating Current (Both Ports Active) | CEL = CER = VIL, Outputs Disabled f = fmax ⁽³⁾ | COM'L | SA LA | 65 65 | 155 110 | 65 65 | 155 110 | mA |
| | (Buil Fulls Active) | I = IWAX' | MIL & IND | SA LA | 65 65 | 190 140 | 65 65 | 190 140 | |
| ISB1 | $ \begin{array}{ll} \text{Standby Current} & \overline{\text{CEL}} = \overline{\text{CER}} = \text{VIH,} \\ \text{(Both Ports - TTL} & \text{f = fMAX}^{(3)} \\ \text{Level Inputs)} \\ \end{array} $ | COM'L | SA LA | 20 20 | 65 35 | 20 20 | 55 35 | mA | |
| | Level inpuis) | | MIL & IND | SA LA | 20 20 | 65 45 | 20 20 | 65 45 | |
| ISB2 | Standby Current \overline{CE} 'A" = VIL and \overline{CE} 'B" = VIH $^{(6)}$ Active Port Outputs Disabled | COM'L | SA LA | 40 40 | 110 75 | 40 40 | 110 75 | mA | |
| | Level Inputs) | f=fMAX ⁽³⁾ | MIL & IND | SA LA | 40 40 | 125 90 | 40 40 | 125 90 | |
| ISB3 | Full Standby Current (Both Ports - All | $\overline{CE}L$ and $\overline{CE}R \ge VCC -0.2V$ $VIN \ge VCC -0.2V$ or $VIN \le 0.2V$, $f = 0^{(4)}$ | COM'L | SA LA | 1.0 0.2 | 15 4 | 1.0 0.2 | 15 4 | mA |
| | CMOS Level Inputs) | | MIL & IND | SA LA | 1.0 0.2 | 30 10 | 1.0 0.2 | 30 10 | |
| ISB4 | Full Standby Current (One Port - All | One Port - All $V_{IN} \ge \overline{V_{CC}} - 0.2V$ or $V_{IN} \le 0.2V$ | COM'L | SA LA | 40 40 | 100 70 | 40 40 | 95 70 | mA |
| | CMOS Level Inputs) | Active Port Outputs Disabled $f = f_{MAX}^{(3)}$ | MIL & IND | SA LA | 40 40 | 110 85 | 40 40 | 110 80 | |

NOTES:

- 1. 'X' in part numbers indicates power rating (SA or LA).
- 2. PLCC Package only
- 3. At f = fMax, address and control lines (except Output Enable) are cycling at the maximum frequency read cycle of 1/trc, and using "AC TEST CONDITIONS" of input levels
- 4. f = 0 means no address or control lines change. Applies only to inputs at CMOS level standby.
- 5. Vcc = 5V, Ta=+25°C for Typ and is not production tested. Vcc pc = 100mA (Typ)
- 6. Port "A" may be either left or right port. Port "B" is opposite from port "A".
- Not available in DIP packages.
- Industrial temperature: for specific speeds, packages and powers contact your sales office.

DC Electrical Characteristics Over the Operating Temperature Supply Voltage Range (Vcc = 5.0V ± 10%)

| | | | 7132SA 7142SA | | 713 714 | | |
|--------|---|---|------------------|------|------------|------|------|
| Symbol | Parameter | Test Conditions | Min. | Max. | Min. | Max. | Unit |
| Iu | Input Leakage Current ⁽¹⁾ | Vcc = 5.5V, Vin = 0V to Vcc | | 10 | | 5 | μΑ |
| ILO | Output Leakage Current | $\frac{\text{Vcc}}{\text{CE}} = 5.5\text{V},$ $\frac{\text{CE}}{\text{CE}} = \text{ViH}, \text{Vout} = 0\text{V to Vcc}$ | | 10 | 1 | 5 | μΑ |
| Vol | Output Low Voltage | IoL = 4mA | | 0.4 | - | 0.4 | V |
| Vol | Open Drain O <u>utput</u> Low Voltage (BUSY) | IoL = 16mA | | 0.5 | 1 | 0.5 | ٧ |
| Vон | Output High Voltage | IOH = -4mA | 2.4 | _ | 2.4 | _ | ٧ |

2692 tbl 05

2692 tbl 06

NOTE:

1. At $Vcc \le 2.0V$ leakages are undefined.

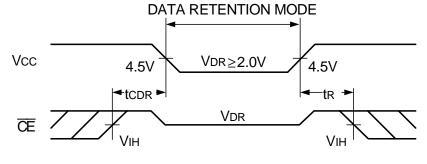
Data Retention Characteristics (LA Version Only)

| Symbol | Parameter | Test Condition | Min. | Typ. ⁽¹⁾ | Max. | Unit | |
|---------------------|--------------------------------------|---------------------------|-------------|---------------------|------|------|----|
| VDR | Vcc for Data Retention | Vcc = 2.0V | | 2.0 | _ | | V |
| ICCDR | Data Retention Current | CE ≥ Vcc -0.2V | Mil. & Ind. | _ | 100 | 4000 | μΑ |
| | | VIN > Vcc -0.2V or | Com'l. | _ | 100 | 1500 | μΑ |
| tcdr ⁽³⁾ | Chip Deselect to Data Retention Time | VIN <u>≤</u> 0.2V | | 0 | _ | | ns |
| tR ⁽³⁾ | Operation Recovery Time | | | trc ⁽²⁾ | _ | _ | ns |

NOTES:

- 1. Vcc = 2V, Ta = +25°C, and is not production tested.
- 2. trc = Read Cycle Time
- 3. This parameter is guaranteed but not production tested.

Data Retention Waveform



2692 drw 05

AC Test Conditions

| Input Pulse Levels | GND to 3.0V |
|-------------------------------|---------------------|
| Input Rise/Fall Times | 3ns Max. |
| Input Timing Reference Levels | 1.5V |
| Output Reference Levels | 1.5V |
| Output Load | Figures 1, 2, and 3 |

2692 tbl 07

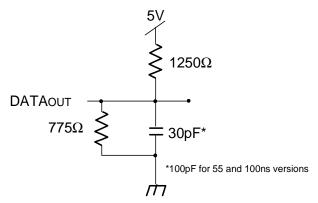


Figure 1. AC Output Test Load

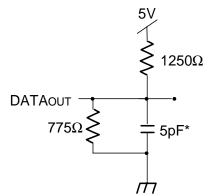


Figure 2. Output Test Load (for thz, tLz, twz, and tow) * Including scope and jig

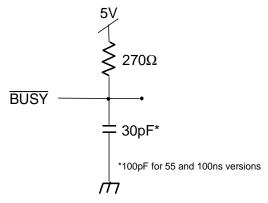


Figure 3. BUSY AC Output Test Load

2692 drw 06

AC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range^(3,5)

| | | 7132X20 ⁽²⁾ 7142X20 ⁽²⁾ Com'l Only | | 7142 Com | 7132X25 ⁽²⁾ 7132X35 7142X25 ⁽²⁾ 7142X35 Com'l, Ind Com'l & & Military Military | | | | | |
|------------|--|--|------|-------------|---|------|------|------|--|--|
| Symbol | Parameter | Min. | Max. | Min. | Max. | Min. | Max. | Unit | | |
| READ CYCLE | | | | | | | | | | |
| trc | Read Cycle Time | 20 | | 25 | _ | 35 | | ns | | |
| taa | Address Access Time | | 20 | - | 25 | | 35 | ns | | |
| tace | Chip Enable Access Time | | 20 | | 25 | | 35 | ns | | |
| taoe | Output Enable Access Time | | 11 | | 12 | | 20 | ns | | |
| tон | Output Hold from Address Change | 3 | | 3 | | 3 | | ns | | |
| tLz | Output Low-Z Time ^(1,4) | 0 | | 0 | | 0 | | ns | | |
| tHZ | Output High-Z Time ^(1,4) | | 10 | | 10 | | 15 | ns | | |
| tpu | Chip Enable to Power Up Time ⁽⁴⁾ | 0 | _ | 0 | _ | 0 | _ | ns | | |
| tpD | Chip Disable to Power Down Time ⁽⁴⁾ | | 20 | _ | 25 | _ | 35 | ns | | |

2692 tbl 08a

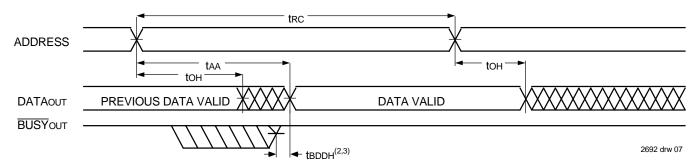
| | | 7132X55 7142X55 Com'l & Military | | 7132X100 7142X100 Com'l & Military | | |
|----------|--|---|------|---|------|------|
| Symbol | Parameter | Min. | Max. | Min. | Max. | Unit |
| READ CYC | CLE | | | | | |
| trc | Read Cycle Time | 55 | _ | 100 | _ | ns |
| taa | Address Access Time | _ | 55 | _ | 100 | ns |
| tace | Chip Enable Access Time | | 55 | 1 | 100 | ns |
| taoe | Output Enable Access Time | | 25 | | 40 | ns |
| tон | Output Hold from Address Change | 3 | _ | 10 | | ns |
| tLZ | Output Low-Z Time ^(1,4) | 5 | _ | 5 | | ns |
| tHZ | Output High-Z Time ^(1,4) | | 25 | | 40 | ns |
| tpu | Chip Enable to Power Up Time (4) | 0 | _ | 0 | | ns |
| tPD | Chip Disable to Power Down Time ⁽⁴⁾ | | 50 | | 50 | ns |

2692 tbl 08b

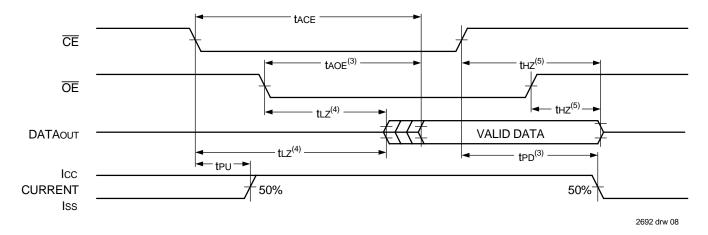
NOTES:

- 1. Transition is measured 0mV from Low or High-Impedance Voltage Output Test Load (Figure 2).
- 2. PLCC package only.
- 3. 'X' in part numbers indicates power rating (SA or LA).
- 4. This parameter is guaranteed by device characterization, but is not production tested.5. Industrial temperature: for specific speeds, packages and powers contact your sales office.

Timing Waveform of Read Cycle No. 1, Either Side⁽¹⁾



Timing Waveform of Read Cycle No. 2, Either Side⁽¹⁾



NOTES:

- 1. $R/\overline{W} = V_{IH}$, $\overline{CE} = V_{IL}$, and is $\overline{OE} = V_{IL}$. Address is valid prior to the coincidental with \overline{CE} transition LOW.
- 2. tbbb delay is required only in the case where the opposite port is completing a write operation to the same address location. For simultaneous read operations, BUSY has no relationship to valid output data.
- 3. Start of valid data depends on which timing becomes effective last tAOE, tACE, tAA, and tBDD.
- 4. Timing depends on which signal is asserted last, $\overline{\sf OE}$ or $\overline{\sf CE}$.
- Timing depends on which signal is de-asserted first, OE or CE.

AC Electrical Characteristics Over the Operating Temperature Supply Voltage Range^(5,6)

| • | | 7132 7142 | X20 ⁽²⁾ X20 ⁽²⁾ I Only | 7132X25 ⁽²⁾ 7142X25 ⁽²⁾ Com'l, Ind & Military | | 7132X35 7142X35 Com'l & Military | | |
|-------------|--|--------------|--|--|------|---|------|------|
| Symbol | Parameter | Min. | Max. | Min. | Max. | Min. | Max. | Unit |
| WRITE CYCLE | | | | | | | | |
| twc | Write Cycle Time ⁽³⁾ | 20 | _ | 25 | _ | 35 | _ | ns |
| tew | Chip Enable to End-of-Write | 15 | _ | 20 | _ | 30 | _ | ns |
| taw | Address Valid to End-of-Write | 15 | | 20 | | 30 | | ns |
| tas | Address Set-up Time | 0 | | 0 | | 0 | | ns |
| twp | Write Pulse Width ⁽⁴⁾ | 15 | _ | 15 | _ | 25 | _ | ns |
| twr | Write Recovery Time | 0 | | 0 | | 0 | | ns |
| tow | Data Valid to End-of-Write | 10 | | 12 | | 15 | | ns |
| tHZ | Output High-Z Time ⁽¹⁾ | _ | 10 | | 10 | | 15 | ns |
| tон | Data Hold Time | 0 | _ | 0 | _ | 0 | | ns |
| twz | Write Enable to Output in High- $\mathbb{Z}^{(1)}$ | _ | 10 | | 10 | _ | 15 | ns |
| tow | Output Active from End-of-Write ⁽¹⁾ | 0 | _ | 0 | _ | 0 | _ | ns |

2692 tbl 09

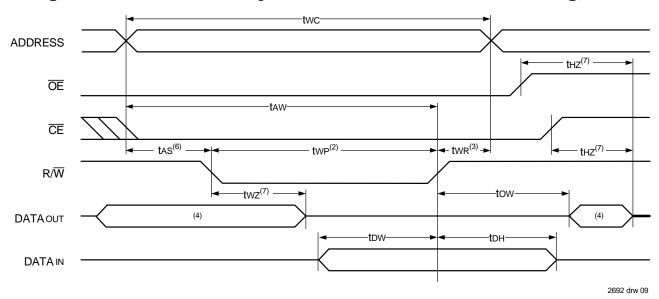
| | | 7142 Con | 2X55 2X55 n'l & tary | 7132X100 7142X100 Com'l & Military | | |
|-------------|---|-------------|-------------------------------|---|------|------|
| Symbol | Parameter | Min. | Max. | Min. | Max. | Unit |
| WRITE CYCLI | E | | | | | |
| twc | Write Cycle Time ⁽³⁾ | 55 | | 100 | _ | ns |
| tew | Chip Enable to End-of-Write | 40 | | 90 | _ | ns |
| taw | Address Valid to End-of-Write | 40 | - | 90 | | ns |
| tas | Address Set-up Time | 0 | - | 0 | _ | ns |
| twp | Write Pulse Width ⁽⁴⁾ | 30 | - | 55 | _ | ns |
| twr | Write Recovery Time | 0 | - | 0 | | ns |
| tow | Data Valid to End-of-Write | 20 | - | 40 | | ns |
| tHZ | Output High-Z Time ⁽¹⁾ | - | 25 | | 40 | ns |
| tDH | Data Hold Time | 0 | - | 0 | _ | ns |
| twz | Write Enable to Output in High-Z ⁽¹⁾ | - | 30 | | 40 | ns |
| tow | Output Active from End-of-Write ⁽¹⁾ | 0 | _ | 0 | _ | ns |

NOTES:

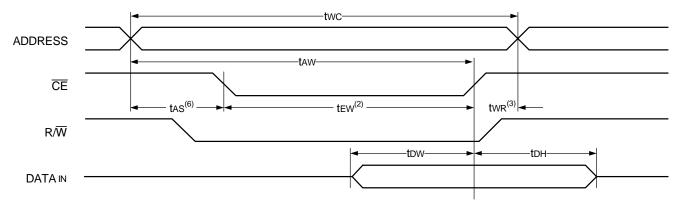
- 1. Transition is measured 0mV from Low or High-impedance voltage with Output Test Load (Figure 2). This parameter is guaranteed by device characterization but is not production tested.
- 2. PLCC package only.
- 3. For Master/Slave combination, two = tbaa + twp, since R/W = VIL must occur after tbaa.
- 4. If \overline{OE} is LOW during a R/ \overline{W} controlled write cycle, the write pulse width must be the larger of twp or (twz + tbw) to allow the I/O drivers to turn off data to be placed on the bus for the required tbw. If \overline{OE} is High during a R/ \overline{W} controlled write cycle, this requirement does not apply and the write pulse can be as short as the specified twp.
- 5. 'X' in part numbers indicates power rating (SA or LA).
- 6. Industrial temperature: for specific speeds, packages and powers contact your sales office.

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Timing Waveform of Write Cycle No. 1, (R/W Controlled Timing)(1,5,8)



Timing Waveform of Write Cycle No. 2, (CE Controlled Timing)(1,5)



NOTES:

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- 1. R/\overline{W} or \overline{CE} must be HIGH during all address transitions.
- 2. A write occurs during the overlap (tew or twp) of \overline{CE} = VIL and R/ \overline{W} = VIL.
- 3. two is measured from the earlier of \overline{CE} or R/\overline{W} going HIGH to the end of the write cycle.
- 4. During this period, the I/O pins are in the output state and input signals must not be applied.
- 5. If the CE LOW transition occurs simultaneously with or after the R/W LOW transition, the outputs remain in the High-impedance state.
- 6. Timing depends on which enable signal (CE or R/W) is asserted last.
- 7. This parameter is determined be device characterization, but is not production tested. Transition is measured 0mV from steady state with the Output Test Load (Figure 2).
- 8. If \overrightarrow{OE} is LOW during a R/W controlled write cycle, the write pulse width must be the larger of twp or (twz + tbw) to allow the I/O drivers to turn off data to be placed on the bus for the required tbw. If \overrightarrow{OE} is HIGH during a R/W controlled write cycle, this requirement does not apply and the write pulse can be as short as the specified twp.

AC Electrical Characteristics Over the Operating Temperature and Supply Voltage Range^(7,8)

| | | 7132X20 ⁽¹⁾ 7142X20 ⁽¹⁾ Com'l Only | | 7132X25 ⁽²⁾ 7142X25 ⁽²⁾ Com'l, Ind & Military | | 7132X35 7142X35 Com'l & Military | | |
|--------------------------------------|--|--|------|--|------|---|------|------|
| Symbol | Parameter | Min. | Max. | Min. | Мах. | Min. | Max. | Unit |
| BUSY Timing | (For Master IDT7132 Only) | | | | | | | |
| t BAA | BUSY Access Time from Address | | 20 | | 20 | — | 20 | ns |
| tbda | BUSY Disable Time from Address | | 20 | _ | 20 | | 20 | ns |
| t BAC | BUSY Access Time from Chip Enable | | 20 | | 20 | | 20 | ns |
| tBDC | BUSY Disable Time from Chip Enable | | 20 | _ | 20 | _ | 20 | ns |
| twdd | Write Pulse to Data Delay ⁽²⁾ | | 50 | _ | 50 | - | 60 | ns |
| twn | Write Hold After BUSY ⁽⁶⁾ | 12 | | 15 | - | 20 | | ns |
| todo | Write Data Valid to Read Data Delay ⁽²⁾ | | 35 | _ | 35 | - | 35 | ns |
| taps | Arbitration Priority Set-up Time ⁽³⁾ | 5 | | 5 | - | 5 | | ns |
| tBDD | BUSY Disable to Valid Data ⁽⁴⁾ | | 25 | _ | 35 | | 35 | ns |
| BUSY Timing (For Slave IDT7142 Only) | | | | | | | | |
| twB | Write to BUSY Input ⁽⁵⁾ | 0 | | 0 | - | 0 | | ns |
| twn | Write Hold After BUSY ⁽⁶⁾ | 12 | | 15 | _ | 20 | | ns |
| twdd | Write Pulse to Data Delay ⁽²⁾ | | 40 | | 50 | | 60 | ns |
| todo | Write Data Valid to Read Data Delay ⁽²⁾ | _ 30 _ 35 _ 3 | | | | 35 | ns | |

2692 tbl 11a

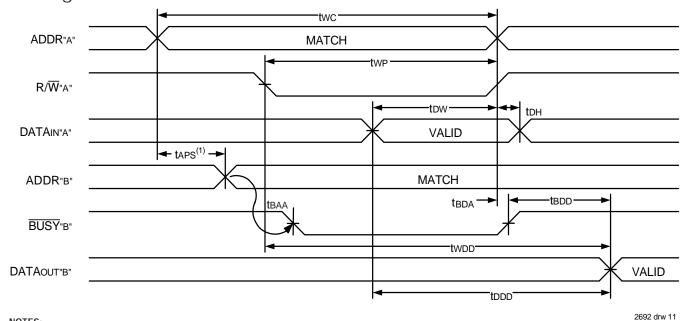
| | | 7142 Con | 7132X55 7142X55 Com'l & Military | | 7132X100 7142X100 Com'l & Military | |
|-------------|--|-------------|---|------|---|------|
| Symbol | Parameter | Min. | Max. | Min. | Max. | Unit |
| BUSY Timing | (For Master IDT7132 Only) | | | | | |
| tbaa | BUSY Access Time from Address | | 30 | | 50 | ns |
| tbda | BUSY Disable Time from Address | _ | 30 | _ | 50 | ns |
| tBAC | BUSY Access Time from Chip Enable | _ | 30 | _ | 50 | ns |
| tBDC | BUSY Disable Time from Chip Enable | _ | 30 | _ | 50 | ns |
| twdd | Write Pulse to Data Delay ⁽²⁾ | _ | 80 | _ | 120 | ns |
| twн | Write Hold After BUSY ⁽⁶⁾ | 20 | - | 20 | _ | ns |
| todd | Write Data Valid to Read Data Delay ⁽²⁾ | _ | 55 | _ | 100 | ns |
| taps | Arbitration Priority Set-up Time ⁽³⁾ | 5 | _ | 5 | _ | ns |
| tBDD | BUSY Disable to Valid Data ⁽⁴⁾ | | 50 | | 65 | ns |
| BUSY Timing | (For Slave IDT7142 Only) | | | | | |
| twB | Write to BUSY Input ⁽⁵⁾ | 0 | | 0 | _ | ns |
| twн | Write Hold After BUSY ⁽⁶⁾ | 20 | _ | 20 | _ | ns |
| twdd | Write Pulse to Data Delay ⁽²⁾ | | 80 | _ | 120 | ns |
| todd | Write Data Valid to Read Data Delay ⁽²⁾ | | 55 | | 100 | ns |

NOTES:

2692 tbl 11b

- 1. PLCC package only.
- 2. Port-to-port delay through RAM cells from the writing port to the reading port, refer to "Timing Waveform of Write with Port -to-Port Read and BUSY."
- 3. To ensure that the earlier of the two ports wins.
- 4. tbdd is a calculated parameter and is the greater of 0, twdd twp (actual) or tddd tdw (actual).
- 5. To ensure that a write cycle is inhibited on port "B" during contention on port "A".
- 6. To ensure that a write cycle is completed on port "B" after contention on port "A".
- 7. 'X' in part numbers indicates power rating (SA or LA).
- 8. Industrial temperature: for specific speeds, packages and powers contact your sales office.

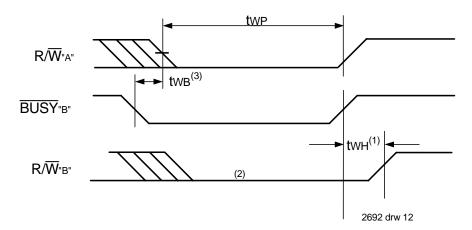
Timing Waveform of Write with Port-to-Port Read and **BUSY**(2,3,4)



NOTES:

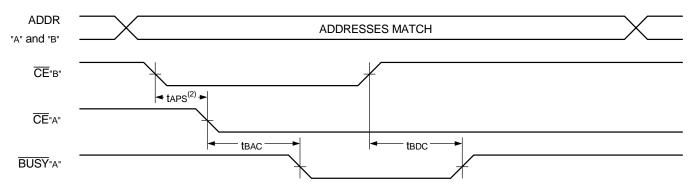
- 1. To ensure that the earlier of the two ports wins. taps is ignored for Slave (IDT7142).
- $\overline{CE}_L = \overline{CE}_R = V_{IL}$
- 3. $\overline{OE} = V_{IL}$ for the reading port.
- 4. All timing is the same for the left and right ports. Port "A" may be either the left or right port. Port "B" is opposite from port "A".

Timing Waveform of Write with **BUSY**(4)



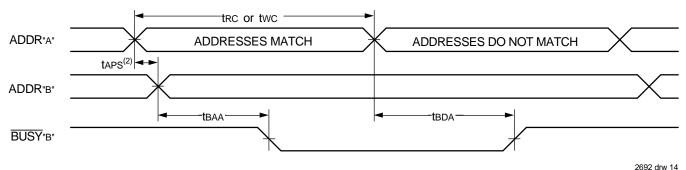
- 1. twn must be met for both BUSY Input (IDT7142, slave) or Output (IDT7132, master).
- 2. BUSY is asserted on port "B" blocking R/W"B", until BUSY"B" goes HIGH.
- 3. twb applies only to the slave version (IDT7142).
- 4. All timing is the same for the left and right ports. Port "A" may be either the left or right port. Port "B" is opposite from port "A".

Timing Waveform of **BUSY** Arbitration Controlled by **CE** Timing⁽¹⁾



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Timing Waveform of $\overline{\textbf{BUSY}}$ Arbitration Controlled by Address Match Timing⁽¹⁾



NOTES:

- 1. All timing is the same for left and right ports. Port "A" may be either left or right port. Port "B" is the opposite from port "A".
- 2. If taps is not satisified, the BUSY will be asserted on one side or the other, but there is no guarantee on which side BUSY will be asserted (7132 only).

Truth Tables

Table I. Non-Contention Read/Write Control⁽⁴⁾

| Left or Right Port ⁽¹⁾ | | | ort ⁽¹⁾ | |
|-----------------------------------|----|----|--------------------|---|
| R/W | ΖĒ | ŌĒ | D0-7 | Function |
| Х | Н | Х | Z | Port Disabled and in Power-Down Mode, ISB2 or ISB4 |
| Х | Н | Χ | Z | $\overline{CER} = \overline{CEL} = VIH$, Power-Down Mode, ISB1 or ISB3 |
| L | L | Χ | DATAIN | Data on Port Written into Memory ⁽²⁾ |
| Н | L | L | DATAout | Data in Memory Output on Port ⁽³⁾ |
| Х | L | Н | Z | High Impedance Outputs |

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NOTES:1. A0L - A10L ≠ A0R - A10R

- 2. If BUSY = L, data is not written.
- 3. If BUSY = L, data may not be valid, see twop and topp timing.
- 4. 'H' = VIH, 'L' = VIL, 'X' = DON'T CARE, 'Z' = HIGH IMPEDANCE

Table II — Address **BUSY** Arbitration

| , a set a cross | | | | | | | |
|-----------------|-----|----------------------|---|------|------------------------------|--|--|
| Inputs | | | Out | puts | | | |
| ΖĒ∟ | CER | AOL-A10L AOR-A10R | BUSYL ⁽¹⁾ BUSYR ⁽¹⁾ | | Function | | |
| Х | Х | NO MATCH | Н | Н | Normal | | |
| Н | Χ | MATCH | Н | Н | Normal | | |
| Х | Н | MATCH | Н | Н | Normal | | |
| L | L | MATCH | (2) | (2) | Write Inhibit ⁽³⁾ | | |

NOTES:

1. Pins BUSYL and BUSYR are both outputs for IDT7132 (master). Both are inputs for

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- IDT7142 (slave). BUSYx outputs on the IDT7132 are open drain, not push-pull outputs. On slaves the BUSYx input internally inhibits writes.
- 2. 'L'if the inputs to the opposite port were stable prior to the address and enable inputs of this port. 'H' if the inputs to the opposite port became stable after the address and enable inputs of this port. If taps is not met, either BUSYL or BUSYR = LOW will result. BUSYL and BUSYR outputs can not be LOW simultaneously.
- 3. Writes to the left port are internally ignored when $\overline{\text{BUSY}}\text{L}$ outputs are driving LOW regardless of actual logic level on the pin. Writes to the right port are internally ignored when BUSYR outputs are driving LOW regardless of actual logic level on the pin.

Functional Description

The IDT7132/IDT7142 provides two ports with separate control, address and I/O pins that permit independent access for reads or writes to any location in memory. The IDT7132/IDT7142 has an automatic power down feature controlled by \overline{CE} . The \overline{CE} controls onchip power down circuitry that permits the respective port to go into a standby mode when not selected (\overline{CE} = VIH). When a port is enabled, access to the entire memory array is permitted.

Busy Logic

Busy Logic provides a hardware indication that both ports of the RAM have accessed the same location at the same time. It also allows one of the two accesses to proceed and signals the other side that the RAM is "Busy". The BUSY pin can then be used to stall the access until the operation on the other side is completed. If a write operation has been attempted from the side that receives a busy indication, the write signal is gated internally to prevent the write from proceeding.

The use of BUSY Logic is not required or desirable for all applications. In some cases it may be useful to logically OR the BUSY outputs together and use any BUSY indication as an interrupt source to flag the event of an illegal or illogical operation.

The BUSY outputs on the IDT7132 RAM master are open drain type outputs and require open drain resistors to operate. If these RAMs are being expanded in depth, then the BUSY indication for the resulting array does not require the use of an external AND gate.

Width Expansion with Busy Logic Master/Slave Arrays

When expanding an SRAM array in width while using BUSY logic, one master part is used to decide which side of the SRAM array will receive a BUSY indication, and to output that indication. Any number of slaves to be addressed in the same address range as the master, use the BUSY signal as a write inhibit signal. Thus on the IDT7132/ IDT7142 SRAMs the BUSY pin is an output if the part is Master (IDT7132). and the BUSY pin is an input if the part is a Slave (IDT7142) as shown in Figure 3.

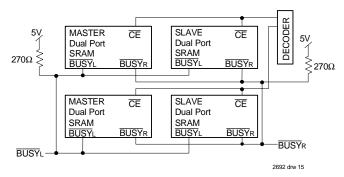
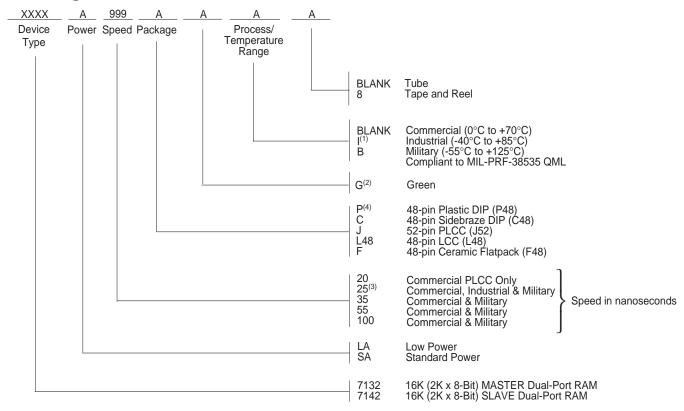


Figure 4. Busy and chip enable routing for both width and depth expansion with IDT7132 (Master) and (Slave) IDT7142 SRAMs.

If two or more master parts were used when expanding in width, a split decision could result with one master indicating BUSY on one side of the array and another master indicating BUSY on one other side of the array. This would inhibit the write operations from one port for part of a word and inhibit the write operations from the other port for the other part of the word.

The BUSY arbitration, on a Master, is based on the chip enable and address signals only. It ignores whether an access is a read or write. In a master/slave array, both address and chip enable must be valid long enough for a BUSY flag to be output from the master before the actual write pulse can be initiated with either the R/W signal or the byte enables. Failure to observe this timing can result in a glitched internal write inhibit signal and corrupted data in the slave.

Ordering Information



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NOTES:

- 1. Industrial temperature range is available. For specific speeds, packages and powers contact your sales office.
- Green parts available. For specific speeds, packages and powers contact your local sales office.
 LEAD FINISH (SnPb) parts are in EOL process. Product Discontinuation Notice PDN# SP-17-02
- 3. 25ns speed grade not available in DIP packages.
- 4. For "P", Plastic DIP, when ordering green package, the suffix is "PDG".

Datasheet Document History

| 03/24/99: | | Initiated datasheet document history |
|-----------|---------------|--|
| | | Converted to new format |
| | | Cosmetic and typographical corrections |
| | Pages 2 and 3 | Added additional notes to pin configurations |
| 06/08/99: | | Changed drawing format |
| 08/26/99: | Page 14 | Changed Busy Logic and Width Expansion copy |
| 11/10/99: | | Replaced IDT logo |
| 01/12/00: | Pages 1 and 2 | Moved full "Description" to page 2 and adjusted page layouts |
| | Page 1 | Added "(LAonly)" to paragraph |
| | Page 2 | Fixed P48-1 body package description |
| | Page 3 | Increased storage temperature parameters |
| | | Clarified TA parameter |
| | Page 4 | DC Electrical parameters—changed wording from "open" to "disabled" |
| | Page 6 | Added asteriks to Figures 1 and 3 in drw 06 |
| | Page 14 | Corrected part numbers |
| | | Changed ±500mV to 0mV in notes |
| | | Datasheet Document History continued on page 16 |

Datasheet Document History (cont'd)

| 06/11/04: | Page 6 Page 4, 7, 9, | Corrected errors in Figure 3 by changing 1250Ω to 270Ω and removing "or Int" and Int Clarified Industrial temp offering for 25ns |
|-----------|-------------------------|--|
| | 11 & 15 | |
| | Page 5 | Removed INT from Vol parameter in DC Electrical Characteristics table |
| | Page 6 | Updated AC Test Conditions Input Rise/Fall Times from 5ns to 3ns |
| 01/17/06: | Page 1 | Added green availability to features |
| | Page 15 | Added green indicator to ordering information |
| | Page 16 | Replaced IDT address with new |
| 10/21/08: | Page 15 | Removed "IDT" from orderable part number |
| 09/20/10: | Page 14 | Corrected BUSY description to indicate open drain outputs |
| 10/03/14: | Page 2 | Removed IDT in reference to fabrication |
| | Page 15 | Added Tape and Reel to Ordering Information |
| | Page 2, 3 & 15 | The package codes P48-1, C48-2, J52-1, L48-1 & F48-1 changed to P48, C48, J52, |
| | D 15 | L48 & F48 respectively to match standard package codes |
| | Page 15 | Add annotation ⁽³⁾ to 25ns speed grade to indicate that 25ns is not available in DIP packages |
| 10/08/14: | Page 15 | Corrected a typo |
| 11/20/15: | Page 15 | Added (4) footnote annotation to the "P" package in the Ordering Information. Added footnote 4, For "P", Plastic DIP, when ordering green package, the suffix is "PDG". |
| 07/03/18: | | Updated L package in the Ordering Information to L48 Product Discontinuation Notice - PDN# SP-17-02 Last time buy expires June 15, 2018 |

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